

New Jersey Semi-Conductor Products, Inc.

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Untitled

2N593

Bidirectional Transistor - Pt 125mw, BVCBO 40V, ICBO 5.0uA, hfe 80typ, Cob 35p typ, NF 16db, fab 600k min

Various

nnp transistors, pnp transistors, transistors

V(BR)CEO (V)=30

V(BR)CBO (V)=40

Absolute Max. Power Diss. (W)=125m

I(CBO) Max. (A)=5.0u

@V(CBO) (V) (Test Condition)=5.0

h(FE) Min. Static Current Gain=30

h(FE) Max. Current gain.=50

@I(C) (A) (Test Condition)=1.0m

@V(CE) (V) (Test Condition)=500m

f(T) Min. (Hz) Transition Freq=600k

@I(C) (A) (Test Condition)=1.0m

@V(CE) (V) (Test Condition)=5.0

Semiconductor Material=Germanium

Structure NPN/PNP=PNP

C(obo) (Max) (F)=35p

@V(CB) (V) (Test Condition)=5.0

Package=TO-5

2N593

Germanium PNP

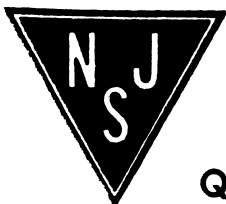
N/A

nnp transistors, pnp transistors, transistors

Category: Germanium Transistor, PNP Transistor, Transistor

MHZ: >0.6 MHZ

volts: 40V



Quality Semi-Conductors